NSN 5961-01-046-4269

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-046-4269 **Inclosure Material:** Ceramic **Overall Length:** 0.565 inches **Overall Height:** 0.565 inches **Overall Width:** 1.656 inches **Mounting Method:** Compression **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 720.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 25.00 milliamperes collector current, dc nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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